# **Schottky Barrier Rectifier** DST2050S, 20A, 50V, TO-277B, Single

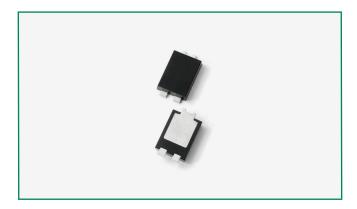
# **DST2050S**



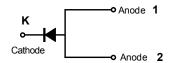








#### Pin out



#### **Description**

Littelfuse DST series Ultra Low V<sub>F</sub> Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industry applications by providing high temperature, low leakage and lower V<sub>E</sub> products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

#### **Features**

- Ultra low forward voltage
- High frequency operation
- MSL: Level 1 unlimited
- High junction temperature capability
- Trench MOS Schottky technology
- Single die in TO-277B Package
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

### **Applications**

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

#### **Maximum Ratings**

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V <sub>RWM</sub>	-	50	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>L</sub> = 125 °C rectangular wave form	20	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	250	А

#### **Electrical Characteristics**

Parameters	Symbol	Test Conditions	Max	Unit	
Forward Voltage Drop*	V <sub>F1</sub>	@20A, Pulse, T <sub>J</sub> = 25 °C	0.65	V	
Forward voltage Drop	V <sub>F2</sub>	@20A, Pulse, T <sub>J</sub> = 125 °C	0.60	V	
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_{R,} T_J = 25 °C$	4	mΛ	
neverse Current	I <sub>R2</sub>	$@V_R = rated V_{R_i} T_J = 125 °C$	180	mA	

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# Schottky Barrier Rectifier DST2050S, 20A, 50V, TO-277B, Single

hermal-Mechanical Specifications				
Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	T <sub>J</sub>		-55 to +150	°C
Storage Temperature	T <sub>stq</sub>		-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	R <sub>thJA</sub>		75	°C/W
Maximum Thermal Resistance Junction to Lead	R <sub>thJL</sub>	DC operation	3.5	°C/W
Approximate Weight	wt		0.08	g
Case Style	TO-277B			

## **Figure 1: Typical Forward Characteristics**

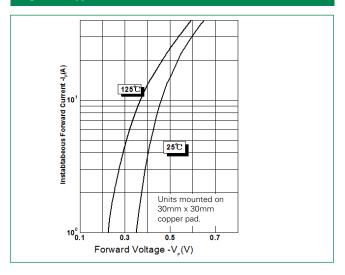
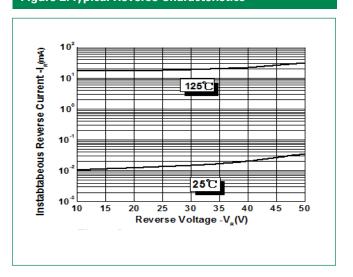
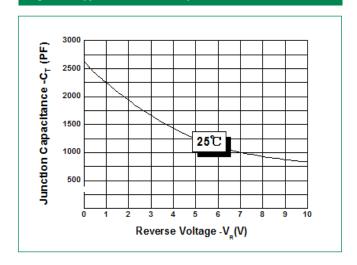


Figure 2: Typical Reverse Characteristics

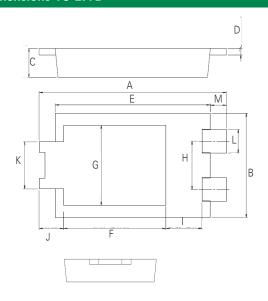


**Figure 3: Typical Junction Capacitance** 



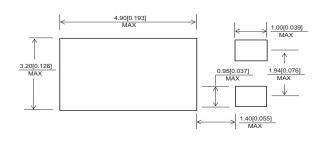
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### **Dimensions-TO-277B**

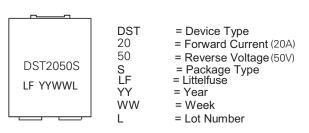


Symbol	Millimeters		
Зуптьог	Min	Тур	Max
Α	6.30	6.50	6.70
В	3.88	3.98	4.08
С	0.95	1.10	1.25
D	0.20	0.25	0.30
E	5.28	5.38	5.48
F	3.40	3.55	3.70
G	2.90	3.05	3.20
Н	1.74	1.84	1.94
1	1.10	1.25	1.40
J	-	0.85	-
K	1.70	1.80	1.90
L	0.85	0.90	0.95
M	-	0.56	-

#### **Mounting Pad Layout**



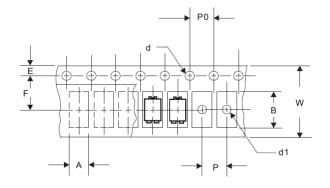
### **Part Numbering and Marking System**



## **Packing Options**

Part Number	Marking	Packing Mode	M.O.Q
DST2050S	DST2050S	5000pcs / Reel	5000

# **Carrier Tape & Reel Specification**



Symbol	Millimeters		
Зунноог	Min	Max	
Α	4.28	4.48	
В	6.80	7.00	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
W	11.70	12.30	

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